Data sheet acquired from Harris Semiconductor SCHS149F

September 1997 - Revised November 2003

## High-Speed CMOS Logic 10- to 4-Line Priority Encoder

### **Features**

- · Buffered Inputs and Outputs
- Typical Propagation Delay: 13ns at V<sub>CC</sub> = 5V, C<sub>L</sub> = 15pF, T<sub>A</sub> = 25°C
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity: N<sub>IL</sub> = 30%, N<sub>IH</sub> = 30% of V<sub>CC</sub> at V<sub>CC</sub> = 5V
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility,
     V<sub>IL</sub>= 0.8V (Max), V<sub>IH</sub> = 2V (Min)
  - CMOS Input Compatibility,  $I_I \le 1\mu A$  at  $V_{OL}$ ,  $V_{OH}$

### Description

The 'HC147 and CD74HCT147 are high speed silicon-gate CMOS devices and are pin-compatible with low power Schottky TTL (LSTTL).

The 'HC147 and CD74HCT147 9-input priority encoders accept data from nine active LOW inputs (I<sub>1</sub> to I<sub>9</sub>) and

provide binary representation on the four active LOW inputs  $(\overline{Y0}$  to  $\overline{Y3})$ . A priority is assigned to each input so that when two or more inputs are simultaneously active, the input with the highest priority is represented on the output, with input line  $l_9$  having the highest priority.

These devices provide the 10-line to 4-line priority encoding function by use of the implied decimal "zero". The "zero" is encoded when all nine data inputs are HIGH, forcing all four outputs HIGH.

## **Ordering Information**

| PART NUMBER  | TEMP. RANGE<br>(°C) | PACKAGE      |
|--------------|---------------------|--------------|
| CD54HC147F3A | -55 to 125          | 16 Ld CERDIP |
| CD74HC147E   | -55 to 125          | 16 Ld PDIP   |
| CD74HC147M   | -55 to 125          | 16 Ld SOIC   |
| CD74HC147MT  | -55 to 125          | 16 Ld SOIC   |
| CD74HC147M96 | -55 to 125          | 16 Ld SOIC   |
| CD74HC147NSR | -55 to 125          | 16 Ld SOP    |
| CD74HC147PW  | -55 to 125          | 16 Ld TSSOP  |
| CD74HC147PWR | -55 to 125          | 16 Ld TSSOP  |
| CD74HC147PWT | -55 to 125          | 16 Ld TSSOP  |
| CD74HCT147E  | -55 to 125          | 16 Ld PDIP   |

NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a small-quantity reel of 250.

### **Pinout**

CD54HC147 (CERDIP)
CD74HC147 (PDIP, SOIC, SOP, TSSOP)
CD74HCT147 (PDIP, TSSOP)
TOP VIEW

 I4
 1

 I5
 2

 I5
 NC

 I6
 3

 I7
 4

 I3
 I3

 I8
 5

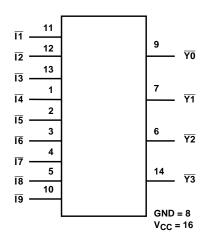
 Y2
 6

 Y1
 7

 GND
 8

 9
 Y0

# Functional Diagram



**TRUTH TABLE** 

|    | INPUTS |    |    |            |           |    |    |            |           |    | OUTPUTS  |    |  |  |  |
|----|--------|----|----|------------|-----------|----|----|------------|-----------|----|----------|----|--|--|--|
| ĪĪ | Ī2     | Ī3 | Ī4 | Ī <u>5</u> | <u>16</u> | Ī7 | Ī8 | Ī <u>9</u> | <u>Y3</u> | Y2 | <u> </u> | Y0 |  |  |  |
| Н  | Н      | Н  | Н  | Н          | Н         | Н  | Н  | Н          | Н         | Н  | Н        | Н  |  |  |  |
| Х  | Х      | Х  | Х  | Х          | Х         | Х  | Х  | Ш          | L         | Н  | Н        | L  |  |  |  |
| Х  | Х      | Х  | Х  | Х          | Х         | Х  | L  | Н          | L         | Н  | Н        | Н  |  |  |  |
| Х  | Х      | Х  | Х  | Х          | Х         | L  | Н  | Н          | Н         | L  | L        | L  |  |  |  |
| Х  | Х      | Х  | Х  | Х          | L         | Н  | Н  | Н          | Н         | L  | L        | Н  |  |  |  |
| Х  | Х      | Х  | Х  | L          | Н         | Н  | Н  | Н          | Н         | L  | Н        | L  |  |  |  |
| Х  | Х      | Х  | L  | Н          | Н         | Н  | Н  | Н          | Н         | L  | Н        | Н  |  |  |  |
| Х  | Х      | L  | Н  | Н          | Н         | Н  | Н  | Н          | Н         | Н  | L        | L  |  |  |  |
| Х  | L      | Н  | Н  | Н          | Н         | Н  | Н  | Н          | Н         | Н  | L        | Н  |  |  |  |
| L  | Н      | Н  | Н  | Н          | Н         | Н  | Н  | Н          | Н         | Н  | Н        | L  |  |  |  |

 $H = High \ Logic \ Level, \ L = Low \ Logic \ Level, \ X = Don't \ Care$ 

## **Absolute Maximum Ratings**

| DC Supply Voltage, V <sub>CC</sub>  | -0.5V to 7V |
|---|-------------|
| DC Input Diode Current, I <sub>IK</sub>                                   |             |
| For $V_1 < -0.5V$ or $V_1 > V_{CC} + 0.5V$                                | ±20mA       |
| DC Output Diode Current, IOK  |             |
| For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$                                | ±20mA       |
| DC Output Source or Sink Current per Output Pin, IO                       |             |
| For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$                                | ±25mA       |
| DC V <sub>CC</sub> or Ground Current, I <sub>CC or</sub> I <sub>GND</sub> |             |

### **Thermal Information**

| Package Thermal Impedance, $\theta_{JA}$ (see Note 1):<br>E (PDIP) Package |
|--|
| NS (SOP) Package   |
| PW (TSSOP) Package 108°C/W   |
| Maximum Junction Temperature   |
| Maximum Storage Temperature Range65°C to 150°C                             |
| Maximum Lead Temperature (Soldering 10s)300°C (SOIC - Lead Tips Only)      |

## **Operating Conditions**

| Temperature Range (T <sub>A</sub> )55°C to 125°C            |
|---|
| Supply Voltage Range, V <sub>CC</sub>                       |
| HC Types2V to 6V  |
| HCT Types   |
| DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub> |
| Input Rise and Fall Time                                    |
| 2V  |
| 4.5V 500ns (Max)  |
| 6V  |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

## **DC Electrical Specifications**

|                                   |  | TE:<br>CONDI                       |                     | v <sub>cc</sub> | 25°C |     |      | -40°C 1 | O 85°C | -55°C TO 125°C |      |       |
|-----------------------------------|--|------------------------------------|---------------------|-----------------|------|-----|------|---------|--------|----------------|------|-------|
| PARAMETER                         | ARAMETER SYMBOL V <sub>I</sub> (V) I <sub>O</sub> (mA) |                                    | I <sub>O</sub> (mA) |                 | MIN  | TYP | MAX  | MIN     | MAX    | MIN            | MAX  | UNITS |
| HC TYPES                          |  |                                    |                     |                 |      |     |      |         |        |                |      |       |
| High Level Input                  | V <sub>IH</sub>  | -                                  | -                   | 2               | 1.5  | -   | -    | 1.5     | -      | 1.5            | -    | V     |
| Voltage                           |  |                                    |                     | 4.5             | 3.15 | -   | -    | 3.15    | -      | 3.15           | -    | V     |
|                                   |  |                                    |                     | 6               | 4.2  | -   | -    | 4.2     | -      | 4.2            | -    | V     |
| Low Level Input<br>Voltage        | V <sub>IL</sub>  | -                                  | -                   | 2               | -    | -   | 0.5  | -       | 0.5    | -              | 0.5  | V     |
|                                   |  |                                    |                     | 4.5             | -    | -   | 1.35 | -       | 1.35   | -              | 1.35 | V     |
|                                   |  |                                    |                     | 6               | -    | -   | 1.8  | -       | 1.8    | -              | 1.8  | V     |
| High Level Output V <sub>OH</sub> | VoH  | V <sub>IH</sub> or V <sub>IL</sub> | -0.02               | 2               | 1.9  | -   | -    | 1.9     | -      | 1.9            | -    | V     |
| Voltage<br>CMOS Loads             |  |                                    | -0.02               | 4.5             | 4.4  | -   | -    | 4.4     | -      | 4.4            | -    | V     |
| CWOS LOAGS                        |  |                                    | -0.02               | 6               | 5.9  | -   | -    | 5.9     | -      | 5.9            | -    | V     |
| High Level Output                 | 7  |                                    | -                   | -               | -    | -   | -    | -       | -      | -              | -    | V     |
| Voltage<br>TTL Loads              |  |                                    | -4                  | 4.5             | 3.98 | -   | -    | 3.84    | -      | 3.7            | -    | V     |
| TTE LOGUS                         |  |                                    | -5.2                | 6               | 5.48 | -   | -    | 5.34    | -      | 5.2            | -    | V     |
| Low Level Output                  | V <sub>OL</sub>  | V <sub>IH</sub> or V <sub>IL</sub> | 0.02                | 2               | -    | -   | 0.1  | -       | 0.1    | -              | 0.1  | V     |
| Voltage<br>CMOS Loads             |  |                                    | 0.02                | 4.5             | -    | -   | 0.1  | -       | 0.1    | -              | 0.1  | V     |
| OWIGO Edads                       |  |                                    | 0.02                | 6               | -    | -   | 0.1  | -       | 0.1    | -              | 0.1  | V     |
| Low Level Output                  | 7  |                                    | -                   | -               | -    | -   | -    | -       | -      | -              | -    | V     |
| Voltage<br>TTL Loads              |  |                                    | 4                   | 4.5             | -    | -   | 0.26 | -       | 0.33   | -              | 0.4  | V     |
| I I L Loads                       |  |                                    | 5.2                 | 6               | -    | -   | 0.26 | -       | 0.33   | -              | 0.4  | V     |
| Input Leakage<br>Current          | IĮ   | V <sub>CC</sub> or<br>GND          | -                   | 6               | -    | -   | ±0.1 | -       | ±1     | -              | ±1   | μΑ    |
| Quiescent Device<br>Current       | lcc  | V <sub>CC</sub> or<br>GND          | 0                   | 6               | -    | -   | 8    | -       | 80     | -              | 160  | μА    |

## DC Electrical Specifications (Continued)

|  |                              | TE:<br>CONDI                       | -                   | Vcc           |      | 25°C |      | -40°C 1 | O 85°C | -55°C T | O 125°C |       |
|--|------------------------------|------------------------------------|---------------------|---------------|------|------|------|---------|--------|---------|---------|-------|
| PARAMETER  | SYMBOL                       | V <sub>I</sub> (V)                 | I <sub>O</sub> (mA) | (S)           | MIN  | TYP  | MAX  | MIN     | MAX    | MIN     | MAX     | UNITS |
| HCT TYPES  |                              |                                    | -                   |               | -    |      | -    | -       | -      |         |         |       |
| High Level Input<br>Voltage  | V <sub>IH</sub>              | -                                  | -                   | 4.5 to<br>5.5 | 2    | -    | -    | 2       | -      | 2       | -       | V     |
| Low Level Input<br>Voltage   | V <sub>IL</sub>              | -                                  | -                   | 4.5 to<br>5.5 | -    | -    | 0.8  | -       | 0.8    | -       | 0.8     | V     |
| High Level Output<br>Voltage<br>CMOS Loads                           | Voн                          | V <sub>IH</sub> or V <sub>IL</sub> | -0.02               | 4.5           | 4.4  | -    | -    | 4.4     | -      | 4.4     | -       | V     |
| High Level Output<br>Voltage<br>TTL Loads                            |                              |                                    | -4                  | 4.5           | 3.98 | -    | -    | 3.84    | -      | 3.7     | -       | V     |
| Low Level Output<br>Voltage<br>CMOS Loads                            | V <sub>OL</sub>              | V <sub>IH</sub> or V <sub>IL</sub> | 0.02                | 4.5           | -    | -    | 0.1  | -       | 0.1    | -       | 0.1     | V     |
| Low Level Output<br>Voltage<br>TTL Loads                             |                              |                                    | 4                   | 4.5           | -    | -    | 0.26 | -       | 0.33   | -       | 0.4     | V     |
| Input Leakage<br>Current   | lį                           | V <sub>CC</sub> and<br>GND         | 0                   | 5.5           | -    |      | ±0.1 | -       | ±1     | -       | ±1      | μΑ    |
| Quiescent Device<br>Current  | Icc                          | V <sub>CC</sub> or<br>GND          | 0                   | 5.5           | -    | -    | 8    | -       | 80     | -       | 160     | μА    |
| Additional Quiescent<br>Device Current Per<br>Input Pin: 1 Unit Load | ΔI <sub>CC</sub><br>(Note 2) | V <sub>CC</sub><br>-2.1            | -                   | 4.5 to<br>5.5 | -    | 100  | 360  | -       | 450    | -       | 490     | μΑ    |

### NOTE:

## **HCT Input Loading Table**

| INPUT  | UNIT LOADS |
|--|------------|
| $\bar{I}_{\overline{1}}, \bar{I}_{\overline{2}}, \bar{I}_{\overline{3}}, \bar{I}_{\overline{6}}, \bar{I}_{\overline{7}}$ | 1.1        |
| Ī <sub>4</sub> , Ī <sub>5</sub> , Ī <sub>8</sub> , Ī <sub>9</sub>  | 1.5        |

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Table, e.g., 360µA max at  $25^{\rm o}C.$ 

## Switching Specifications Input $t_{\text{r}},\,t_{\text{f}}=6\text{ns}$

|  |                                     | TEST                  |                     | 25°C |     |     | -40°C TO 85°C |     | -55°C TO 125°C |     |       |
|--|-------------------------------------|-----------------------|---------------------|------|-----|-----|---------------|-----|----------------|-----|-------|
| PARAMETER  | SYMBOL                              | CONDITIONS            | V <sub>CC</sub> (V) | MIN  | TYP | MAX | MIN           | MAX | MIN            | MAX | UNITS |
| HC TYPES   |                                     |                       |                     |      |     |     |               |     |                |     |       |
| Propagation Delay,<br>Input to Output (Figure 1) | t <sub>PLH</sub> , t <sub>PHL</sub> | C <sub>L</sub> = 50pF | 2                   | -    | -   | 160 | -             | 200 | -              | 240 | ns    |
|  |                                     |                       | 4.5                 | -    | -   | 32  | -             | 40  | -              | 48  | ns    |
|  |                                     |                       | 5                   | -    | 13  | -   | -             | -   | =              | -   | ns    |
|  |                                     |                       | 6                   | -    | -   | 27  | -             | 34  | -              | 41  | ns    |
| Transition Times                                 | t <sub>TLH</sub> , t <sub>THL</sub> | C <sub>L</sub> = 50pF | 2                   | -    | -   | 75  | -             | 95  | -              | 110 | ns    |
| (Figure 1)                                       |                                     |                       | 4.5                 | -    | -   | 15  | -             | 19  | -              | 22  | ns    |
|  |                                     |                       | 6                   | -    | -   | 13  | -             | 16  | -              | 19  | ns    |
| Input Capacitance                                | C <sub>IN</sub>                     | -                     | -                   | -    | -   | 10  | -             | 10  | =              | 10  | pF    |

<sup>2.</sup> For dual-supply systems theoretical worst case ( $V_I$  = 2.4V,  $V_{CC}$  = 5.5V) specification is 1.8mA.

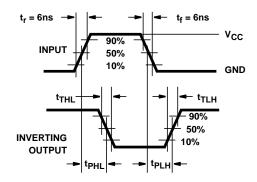
## Switching Specifications Input $t_r$ , $t_f = 6ns$ (Continued)

|  |                                     | TEST                  |                     |     | 25°C |     | -40°C T | O 85°C | -55°C T |     |       |
|--|-------------------------------------|-----------------------|---------------------|-----|------|-----|---------|--------|---------|-----|-------|
| PARAMETER                                  | SYMBOL CONDITION                    |                       | V <sub>CC</sub> (V) | MIN | TYP  | MAX | MIN     | MAX    | MIN     | MAX | UNITS |
| Power Dissipation Capacitance (Notes 3, 4) | C <sub>PD</sub>                     | -                     | 5                   | -   | 32   | -   | -       | -      | -       | -   | pF    |
| HCT TYPES                                  |                                     |                       |                     |     |      |     |         |        |         |     |       |
| Propagation Delay,                         | t <sub>PLH</sub> , t <sub>PHL</sub> | C <sub>L</sub> = 50pF | 4.5                 | -   | -    | 35  | -       | 44     | -       | 53  | ns    |
| Input to Output (Figure 2)                 |                                     |                       | 5                   | -   | 14   | -   | -       | -      | -       | -   | ns    |
| Transition Times (Figure 2)                | t <sub>TLH</sub> , t <sub>THL</sub> | C <sub>L</sub> = 50pF | 4.5                 | -   | -    | 15  | -       | 19     | -       | 22  | ns    |
| Input Capacitance                          | C <sub>IN</sub>                     | =                     | =                   | -   | -    | 10  | -       | 10     | -       | 10  | pF    |
| Power Dissipation Capacitance (Notes 3, 4) | C <sub>PD</sub>                     | -                     | 5                   | -   | 42   | -   | -       | -      | -       | -   | pF    |

#### NOTES:

- 3.  $C_{\mbox{\scriptsize PD}}$  is used to determine the dynamic power consumption, per gate.
- 4.  $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$  where  $f_i = Input$  Frequency,  $C_L = Output$  Load Capacitance,  $V_{CC} = Supply$  Voltage.

### Test Circuits and Waveforms



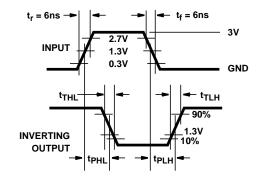


FIGURE 6. HC AND HCU TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC

FIGURE 7. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

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#### **PACKAGING INFORMATION**

| Orderable Device | Status (1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan            | Lead finish/<br>Ball material | MSL Peak Temp      | Op Temp (°C) | Device Marking<br>(4/5)   | Samples |
|------------------|------------|--------------|--------------------|------|----------------|---------------------|-------------------------------|--------------------|--------------|---------------------------|---------|
| 8406401EA        | ACTIVE     | CDIP         | J                  | 16   | 1              | Non-RoHS<br>& Green | SNPB                          | N / A for Pkg Type | -55 to 125   | 8406401EA<br>CD54HC147F3A | Samples |
| CD54HC147F3A     | ACTIVE     | CDIP         | J                  | 16   | 1              | Non-RoHS<br>& Green | SNPB                          | N / A for Pkg Type | -55 to 125   | 8406401EA<br>CD54HC147F3A | Samples |
| CD74HC147E       | ACTIVE     | PDIP         | N                  | 16   | 25             | RoHS & Green        | NIPDAU                        | N / A for Pkg Type | -55 to 125   | CD74HC147E                | Samples |
| CD74HC147M       | ACTIVE     | SOIC         | D                  | 16   | 40             | RoHS & Green        | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | HC147M                    | Samples |
| CD74HC147M96     | ACTIVE     | SOIC         | D                  | 16   | 2500           | RoHS & Green        | NIPDAU   SN                   | Level-1-260C-UNLIM | -55 to 125   | HC147M                    | Samples |
| CD74HC147M96E4   | ACTIVE     | SOIC         | D                  | 16   | 2500           | RoHS & Green        | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | HC147M                    | Samples |
| CD74HC147MT      | ACTIVE     | SOIC         | D                  | 16   | 250            | RoHS & Green        | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | HC147M                    | Samples |
| CD74HC147PW      | ACTIVE     | TSSOP        | PW                 | 16   | 90             | RoHS & Green        | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | HJ147                     | Samples |
| CD74HC147PWR     | ACTIVE     | TSSOP        | PW                 | 16   | 2000           | RoHS & Green        | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | HJ147                     | Samples |
| CD74HC147PWT     | ACTIVE     | TSSOP        | PW                 | 16   | 250            | RoHS & Green        | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | HJ147                     | Samples |
| CD74HCT147E      | ACTIVE     | PDIP         | N                  | 16   | 25             | RoHS & Green        | NIPDAU                        | N / A for Pkg Type | -55 to 125   | CD74HCT147E               | Samples |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

## PACKAGE OPTION ADDENDUM

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(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF CD54HC147, CD74HC147:

Catalog: CD74HC147

Military: CD54HC147

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

• Military - QML certified for Military and Defense Applications

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### TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width     |
|----|---|
| В0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device       | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|--------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| CD74HC147M96 | SOIC            | D                  | 16 | 2500 | 330.0                    | 16.4                     | 6.5        | 10.3       | 2.1        | 8.0        | 16.0      | Q1               |
| CD74HC147M96 | SOIC            | D                  | 16 | 2500 | 330.0                    | 16.4                     | 6.6        | 9.3        | 2.1        | 8.0        | 16.0      | Q1               |
| CD74HC147M96 | SOIC            | D                  | 16 | 2500 | 330.0                    | 16.4                     | 6.5        | 10.3       | 2.1        | 8.0        | 16.0      | Q1               |
| CD74HC147PWR | TSSOP           | PW                 | 16 | 2000 | 330.0                    | 12.4                     | 6.9        | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |
| CD74HC147PWT | TSSOP           | PW                 | 16 | 250  | 330.0                    | 12.4                     | 6.9        | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |



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#### \*All dimensions are nominal

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|----------------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| Device                           | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
| CD74HC147M96                     | SOIC         | D               | 16   | 2500 | 356.0       | 356.0      | 35.0        |
| CD74HC147M96                     | SOIC         | D               | 16   | 2500 | 366.0       | 364.0      | 50.0        |
| CD74HC147M96                     | SOIC         | D               | 16   | 2500 | 340.5       | 336.1      | 32.0        |
| CD74HC147PWR                     | TSSOP        | PW              | 16   | 2000 | 356.0       | 356.0      | 35.0        |
| CD74HC147PWT                     | TSSOP        | PW              | 16   | 250  | 356.0       | 356.0      | 35.0        |

## **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



\*All dimensions are nominal

| Device      | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|-------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| CD74HC147E  | N            | PDIP         | 16   | 25  | 506    | 13.97  | 11230  | 4.32   |
| CD74HC147E  | N            | PDIP         | 16   | 25  | 506    | 13.97  | 11230  | 4.32   |
| CD74HC147M  | D            | SOIC         | 16   | 40  | 507    | 8      | 3940   | 4.32   |
| CD74HC147PW | PW           | TSSOP        | 16   | 90  | 530    | 10.2   | 3600   | 3.5    |
| CD74HCT147E | N            | PDIP         | 16   | 25  | 506    | 13.97  | 11230  | 4.32   |
| CD74HCT147E | N            | PDIP         | 16   | 25  | 506    | 13.97  | 11230  | 4.32   |

## 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



## D (R-PDS0-G16)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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